

# 2CL3509、2CL3512

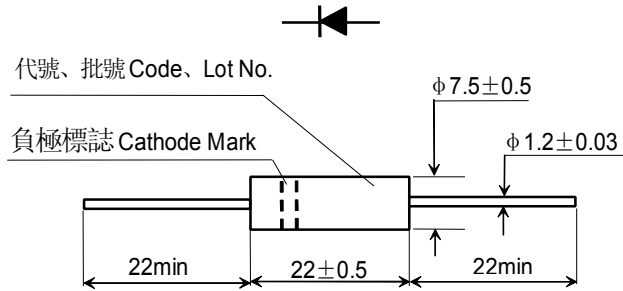
## 微波爐用高壓二極管 High Voltage Diodes for Micro-wave Oven

### ■特徵 Features

- $I_{F(AV)}$  350mA
- $V_{RRM}$  9kV, 12kV
- 高可靠性 High reliability

### ■外形尺寸和印記 Outline Dimensions and Mark

單位 Unit: mm



### ■用途 Applications

- 微波爐及其他電子設備高壓電源整流用  
Rectification for high voltage power supply of magnetron in Micro wave oven and others

型號 Type	代號 Code	負極標誌 Cathode Mark
2CL3509	T3509	
2CL3512	T3512	

### ■極限值 (絕對最大額定值)

#### Limiting Values (Absolute Maximum Rating)

參數名稱 Item	符號 Symbol	單位 Unit	2CL3509	2CL3512
反向重複峰值電壓 Repetitive Peak Reverse Voltage	$V_{RRM}$	kV	9	12
正向平均電流 Average Forward Current	$I_{F(AV)}$	mA	350	(正弦半波 50Hz, 電阻負載, $T_a \leq 60^\circ\text{C}$ *) (50Hz Half-sine wave, Resistance load, $T_a \leq 60^\circ\text{C}$ )
正向浪湧電流 Forward Surge Current	$I_{FSM}$	A	30	(正弦半波 50Hz, 一個周期, $T_a = 25^\circ\text{C}$ ) (50Hz Half-sine wave, 1 cycle, $T_a = 25^\circ\text{C}$ )
反向浪湧電流 Reverse Surge Current	$I_{RSM}$	mA	100	(方波、 $W_p = 1\text{ms}$ , 單脈衝, $T_a = 25^\circ\text{C}$ ) ( $W_p = 1\text{ms}$ , Rectangular-wave, One-shot, $T_a = 25^\circ\text{C}$ )
有效結溫 Virtual Junction Temperature	$T_{(vj)}$	$^\circ\text{C}$	130	
貯存溫度 Storage Temperature	$T_{stg}$	$^\circ\text{C}$	-40 ~ +130	

\* 散熱方式: 將負極端子固定在厚度為0.6mm,面積為50mm×50mm以上的散熱片上,風冷條件: 0.5m/s

Cooling Requirement: Cathode terminal is fastened to radiating fin that size is more than 50mm×50mm×0.6mm Wind-cooled velocity is more than 0.5m/s

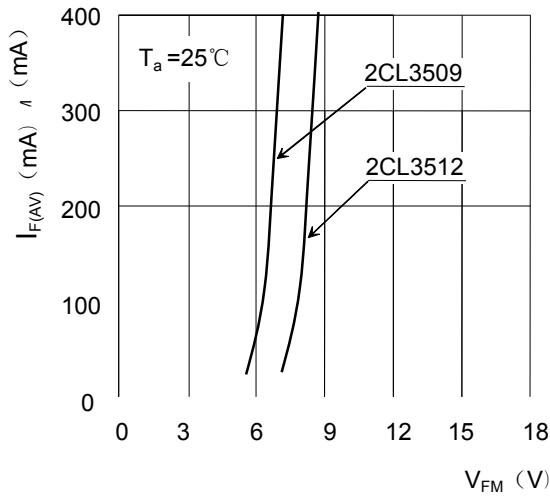
### ■電特性 ( $T_a = 25^\circ\text{C}$ 除非另有規定)

#### Electrical Characteristics ( $T_a = 25^\circ\text{C}$ Unless otherwise specified)

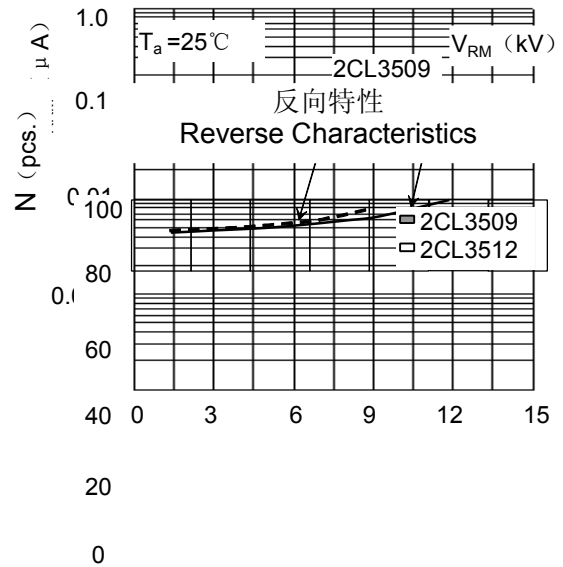
參數名稱 Item	符號 Symbol	單位 Unit	測試條件 Test Condition	2CL3509	2CL3512
正向峰值電壓 Peak Forward Voltage	$V_{FM}$	V	$I_{FM} = 350\text{mA}$	$\leq 9$	$\leq 10$
反向峰值電流 Peak Reverse Current	$I_{RRM1}$	$\mu\text{A}$	$V_{RM} = V_{RRM}$	$\leq 5$	
雪崩擊穿電壓 Avalanche Breakdown Voltage	$V_{(BR)}$	kV	$I_R = 100\mu\text{A}$	$\geq 9.5$	$\geq 12.5$

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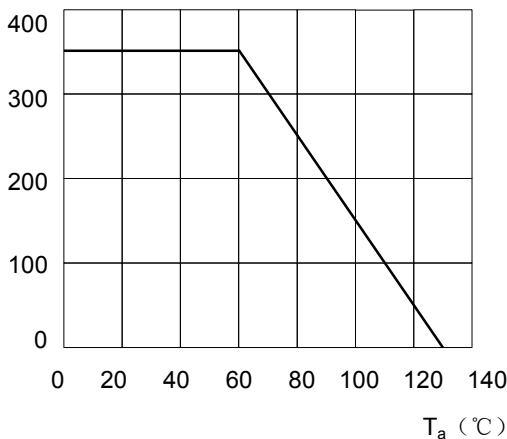
## ■特性曲線 (典型) Characteristics(Typical)



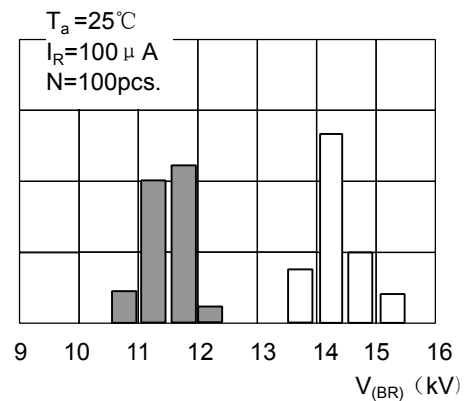
正向特性  
Forward Characteristics



反向特性  
Reverse Characteristics

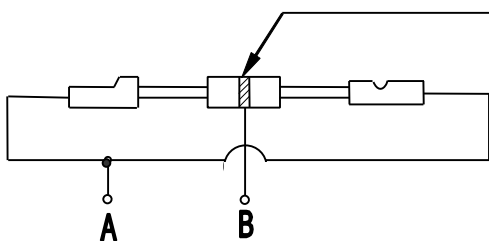


正向平均電流降額曲線  
 $I_{F(AV)} - T_a$  Derating



擊穿電壓分佈  
Breakdown Voltage Distribution

## ●安全試驗 Safety Test



寬 3mm 金屬箔卷在管體中央

3mm Wide metal film is rolled on the surface middle of diode body

- 1.絕緣電阻試驗: AB 之間施加 500V 直流電壓, 用絕緣電阻表測, 絕緣電阻大於 1000MΩ。
- 2.耐壓強度試驗: 在絕緣油中進行, AB 之間施加峰值為 15kV 的正弦半波電壓、1 分鐘, 無擊穿或飛弧。

- 1.Insulation Resistance Test:500V DC voltage is added between A and B. The measurement by insulation resistance meter is big than 1000MΩ .
- 2.Resistance To Voltage Strength Test: 15kV half-sine wave voltage is added between A and B for one minute and no breakdown or arc in insulation oil.